

# CY54FCT245T, CY74FCT245T 8-BIT TRANSCEIVERS WITH 3-STATE OUTPUTS

SCCS018B – MAY 1994 – REVISED NOVEMBER 2001

[查询"5962-9221401M2A"供应商](#)

- Function, Pinout, and Drive Compatible With FCT and F Logic
- Reduced  $V_{OH}$  (Typically = 3.3 V) Versions of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- $I_{off}$  Supports Partial-Power-Down Mode Operation
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)
- Matched Rise and Fall Times
- Fully Compatible With TTL Input and Output Logic Levels
- CY54FCT245T
  - 48-mA Output Sink Current
  - 12-mA Output Source Current
- CY74FCT245T
  - 64-mA Output Sink Current
  - 32-mA Output Source Current
- 3-State Outputs

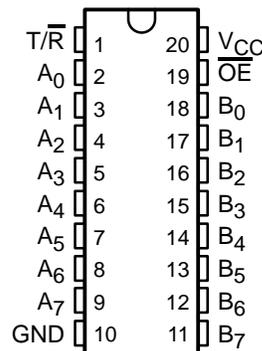
## description

The 'FCT245T devices contain eight noninverting bidirectional buffers with 3-state outputs and are intended for bus-oriented applications.

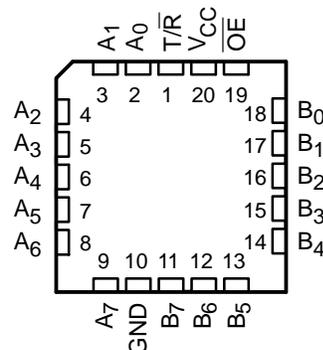
The transmit/receive ( $T/\bar{R}$ ) input determines the direction of data flow through these bidirectional transceivers. Transmit (active high) enables data from A ports to B ports. The output enable ( $\overline{OE}$ ), when high, disables both the A and B ports by putting them in the high-impedance state.

These devices are fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

CY54FCT245T . . . D PACKAGE  
CY74FCT245T . . . P, Q, OR SO PACKAGE  
(TOP VIEW)



CY54FCT245T . . . L PACKAGE  
(TOP VIEW)



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS  
INSTRUMENTS**

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# CY54FCT245T, CY74FCT245T

## 8-BIT TRANSCEIVERS

### WITH 3-STATE OUTPUTS

SCC9587 1992 RELEASE UNDER E.O. 14176

#### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE†		SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	QSOP – Q	Tape and reel	3.8	CY74FCT245DTQCT	FCT245D
	QSOP – Q	Tape and reel	4.1	CY74FCT245CTQCT	FCT245C
	SOIC – SO	Tube	4.1	CY74FCT245CTSOC	FCT245C
		Tape and reel	4.1	CY74FCT245CTSOCT	
	DIP – P	Tube	4.6	CY74FCT245ATPC	CY74FCT245ATPC
	QSOP – Q	Tape and reel	4.6	CY74FCT245ATQCT	FCT245A
	SOIC – SO	Tube	4.6	CY74FCT245ATSOC	FCT245A
		Tape and reel	4.6	CY74FCT245ATSOCT	
	QSOP – Q	Tape and reel	7	CY74FCT245TQCT	FCT245
SOIC – SO	Tube	7	CY74FCT245TSOC	FCT245	
	Tape and reel	7	CY74FCT245TSOCT		
-55°C to 125°C	CDIP – D	Tube	4.5	CY54FCT245CTDMB	
	LCC – L	Tube	4.5	CY54FCT245CTLMB	
	CDIP – D	Tube	4.9	CY54FCT245ATDMB	
	LCC – L	Tube	4.9	CY54FCT245ATLMB	
	CDIP – D	Tube	7.5	CY54FCT245TDMB	
	LCC – L	Tube	7.5	CY54FCT245TLMB	

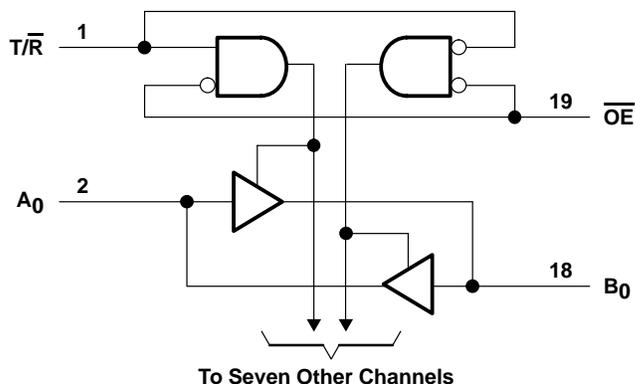
† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).

#### FUNCTION TABLE

INPUTS		OPERATION
$\overline{OE}$	T/R	
L	L	B data to bus A
L	H	A data to bus B
H	X	Z

H = High logic level, L = Low logic level,  
X = Don't care, Z = High-impedance state

#### logic diagram (positive logic)





# CY54FCT245T, CY74FCT245T

## 8-BIT TRANSCEIVERS

### WITH 3-STATE OUTPUTS

SCCS 081106 0902 RELEASED BY SEMTECH

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	CY54FCT245T		CY74FCT245T		UNIT	
		MIN	TYP†	MAX	MIN		TYP†
V <sub>IK</sub>	V <sub>CC</sub> = 4.5 V, I <sub>IN</sub> = -18 mA	-0.7	-1.2			V	
	V <sub>CC</sub> = 4.75 V, I <sub>IN</sub> = -18 mA				-0.7		-1.2
V <sub>OH</sub>	V <sub>CC</sub> = 4.5 V, I <sub>OH</sub> = -12 mA	2.4	3.3			V	
	V <sub>CC</sub> = 4.75 V	I <sub>OH</sub> = -32 mA			2		
		I <sub>OH</sub> = -15 mA			2.4		3.3
V <sub>OL</sub>	V <sub>CC</sub> = 4.5 V, I <sub>OL</sub> = 48 mA	0.3	0.55			V	
	V <sub>CC</sub> = 4.75 V, I <sub>OL</sub> = 64 mA				0.3		0.55
V <sub>hys</sub>	All inputs	0.2			0.2	V	
I <sub>I</sub>	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = V <sub>CC</sub>			5		μA	
	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> = V <sub>CC</sub>				5		
I <sub>IH</sub>	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 2.7 V			±1		μA	
	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> = 2.7 V				±1		
I <sub>IL</sub>	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 0.5 V			±1		μA	
	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> = 0.5 V				±1		
I <sub>OZH</sub>	V <sub>CC</sub> = 5.5 V, V <sub>OUT</sub> = 2.7 V			10		μA	
	V <sub>CC</sub> = 5.25 V, V <sub>OUT</sub> = 2.7 V				10		
I <sub>OZL</sub>	V <sub>CC</sub> = 5.5 V, V <sub>OUT</sub> = 0.5 V			-10		μA	
	V <sub>CC</sub> = 5.25 V, V <sub>OUT</sub> = 0.5 V				-10		
I <sub>OS</sub> ‡	V <sub>CC</sub> = 5.5 V, V <sub>OUT</sub> = 0 V	-60	-120	-225		mA	
	V <sub>CC</sub> = 5.25 V, V <sub>OUT</sub> = 0 V				-60		-120
I <sub>off</sub>	V <sub>CC</sub> = 0 V, V <sub>OUT</sub> = 4.5 V			±1		±1	μA
I <sub>CC</sub>	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> ≤ 0.2 V, V <sub>IN</sub> ≥ V <sub>CC</sub> - 0.2 V	0.1	0.2			mA	
	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> ≤ 0.2 V, V <sub>IN</sub> ≥ V <sub>CC</sub> - 0.2 V				0.1		0.2
ΔI <sub>CC</sub>	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 3.4 V <sup>§</sup> , f <sub>1</sub> = 0, Outputs open	0.5	2			mA	
	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> = 3.4 V <sup>§</sup> , f <sub>1</sub> = 0, Outputs open				0.5		2
I <sub>CCD</sub> ¶	V <sub>CC</sub> = 5.5 V, One input switching at 50% duty cycle, Outputs open, T/R or OE = GND and V <sub>IN</sub> ≤ 0.2 V or V <sub>IN</sub> ≥ V <sub>CC</sub> - 0.2 V	0.06	0.12			mA/ MHz	
	V <sub>CC</sub> = 5.25 V, One input switching at 50% duty cycle, Outputs open, T/R or OE = GND and V <sub>IN</sub> ≤ 0.2 V or V <sub>IN</sub> ≥ V <sub>CC</sub> - 0.2 V				0.06		0.12

† Typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C.

‡ Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, I<sub>OS</sub> tests should be performed last.

§ Per TTL-driven input (V<sub>IN</sub> = 3.4 V); all other inputs at V<sub>CC</sub> or GND

¶ This parameter is derived for use in total power-supply calculations.



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**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)**

PARAMETER	TEST CONDITIONS			CY54FCT245T		CY74FCT245T		UNIT
				MIN	TYP†	MAX	MIN	
I <sub>C</sub> #	V <sub>CC</sub> = 5.5 V, Outputs open, T/R or OE = GND	One bit switching at f <sub>1</sub> = 10 MHz at 50% duty cycle	V <sub>IN</sub> ≤ 0.2 V or V <sub>IN</sub> ≥ V <sub>CC</sub> – 0.2 V	0.7	1.4			mA
			V <sub>IN</sub> = 3.4 V or GND	1.2	3.4			
		Eight bits switching at f <sub>1</sub> = 2.5 MHz at 50% duty cycle	V <sub>IN</sub> ≤ 0.2V or V <sub>IN</sub> ≥ V <sub>CC</sub> – 0.2 V	1.3	2.6			
			V <sub>IN</sub> = 3.4 V or GND	3.3	10.6			
	V <sub>CC</sub> = 5.25 V, Outputs open, T/R or OE = GND	One bit switching at f <sub>1</sub> = 10 MHz at 50% duty cycle	V <sub>IN</sub> ≤ 0.2 V or V <sub>IN</sub> ≥ V <sub>CC</sub> – 0.2 V			0.7	1.4	
			V <sub>IN</sub> = 3.4 V or GND			1.2	3.4	
		Eight bits switching at f <sub>1</sub> = 2.5 MHz at 50% duty cycle	V <sub>IN</sub> ≤ 0.2V or V <sub>IN</sub> ≥ V <sub>CC</sub> – 0.2 V			1.3	2.6	
			V <sub>IN</sub> = 3.4 V or GND			3.3	10.6	
C <sub>i</sub>				5	10	5	10	pF
C <sub>o</sub>				9	12	9	12	pF

† Typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C.

# I<sub>C</sub> = I<sub>CC</sub> + ΔI<sub>CC</sub> × D<sub>H</sub> × N<sub>T</sub> + I<sub>CCD</sub> (f<sub>0</sub>/2 + f<sub>1</sub> × N<sub>1</sub>)

Where:

I<sub>C</sub> = Total supply current

I<sub>CC</sub> = Power-supply current with CMOS input levels

ΔI<sub>CC</sub> = Power-supply current for a TTL high input (V<sub>IN</sub> = 3.4 V)

D<sub>H</sub> = Duty cycle for TTL inputs high

N<sub>T</sub> = Number of TTL inputs at D<sub>H</sub>

I<sub>CCD</sub> = Dynamic current caused by an input transition pair (HLH or LHL)

f<sub>0</sub> = Clock frequency for registered devices, otherwise zero

f<sub>1</sub> = Input signal frequency

N<sub>1</sub> = Number of inputs changing at f<sub>1</sub>

All currents are in milliamperes and all frequencies are in megahertz.

|| Values for these conditions are examples of the I<sub>CC</sub> formula.



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**switching characteristics over operating free-air temperature range (see Figure 1)**

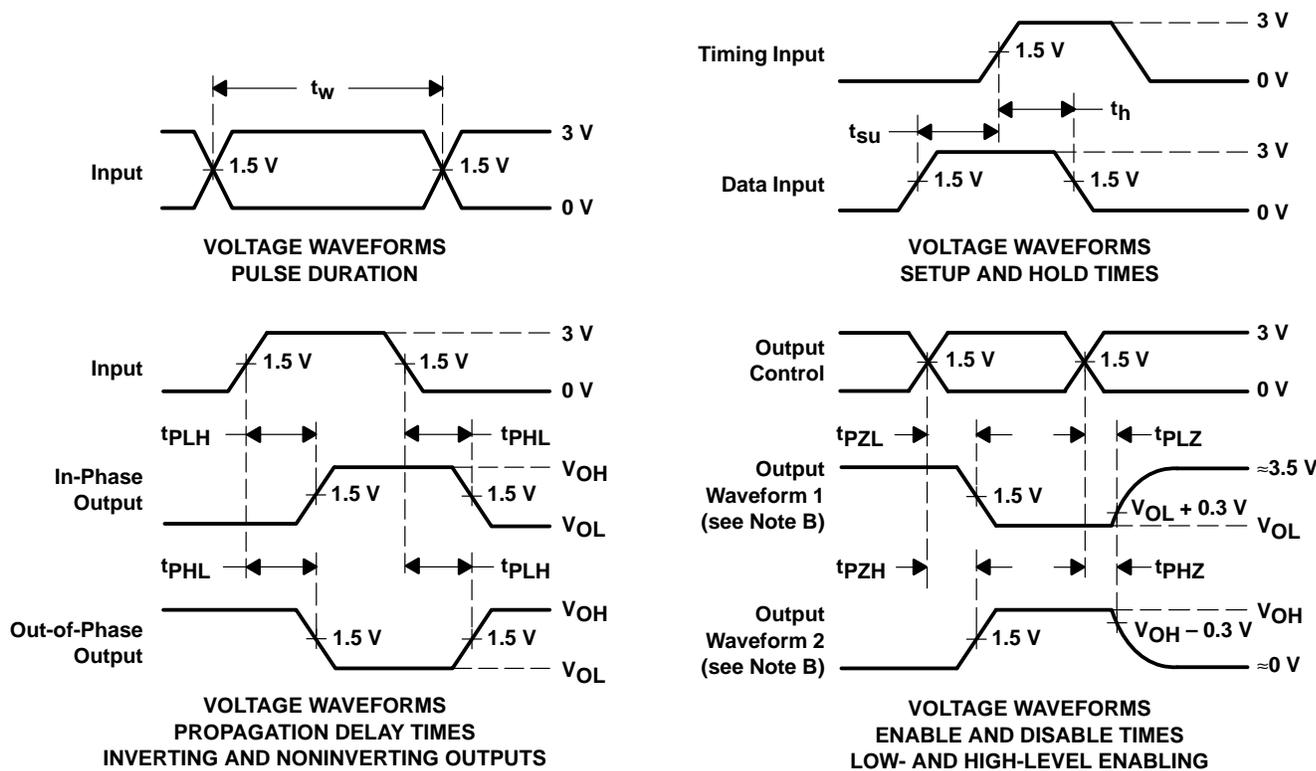
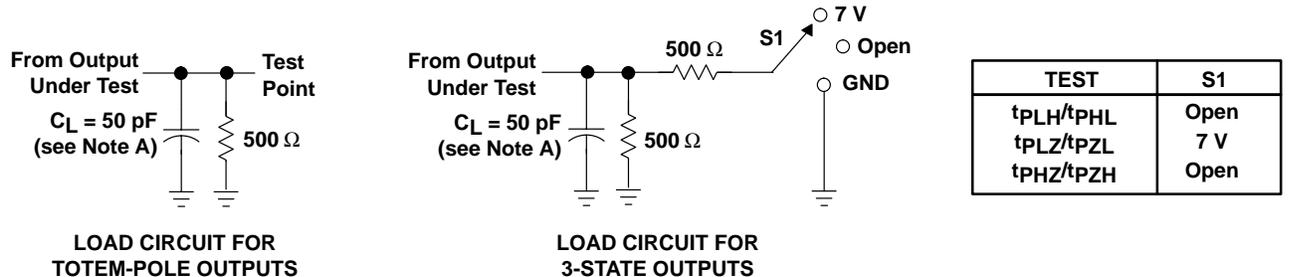
PARAMETER	FROM (INPUT)	TO (OUTPUT)	CY54FCT245T		CY54FCT245AT		CY54FCT245CT		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>PLH</sub>	A or B	B or A	1.5	7.5	1.5	4.9	1.5	4.5	ns
t <sub>PHL</sub>			1.5	7.5	1.5	4.9	1.5	4.5	
t <sub>PZH</sub>	$\overline{OE}$ or T/ $\overline{R}$	A or B	1.5	10	1.5	6.5	1.5	6.2	ns
t <sub>PZL</sub>			1.5	10	1.5	6.5	1.5	6.2	
t <sub>PHZ</sub>	$\overline{OE}$ or T/ $\overline{R}$	A or B	1.5	10	1.5	6	1.5	5.2	ns
t <sub>PLZ</sub>			1.5	10	1.5	6	1.5	5.2	

**switching characteristics over operating free-air temperature range (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	CY74FCT245T		CY74FCT245AT		CY74FCT245CT		CY74FCT245DT		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>PLH</sub>	A or B	B or A	1.5	7	1.5	4.6	1.5	4.1	1.5	3.8	ns
t <sub>PHL</sub>			1.5	7	1.5	4.6	1.5	4.1	1.5	3.8	
t <sub>PZH</sub>	$\overline{OE}$ or T/ $\overline{R}$	A or B	1.5	9.5	1.5	6.2	1.5	5.8	1.5	5	ns
t <sub>PZL</sub>			1.5	9.5	1.5	6.2	1.5	5.8	1.5	5	
t <sub>PHZ</sub>	$\overline{OE}$ or T/ $\overline{R}$	A or B	1.5	7.5	1.5	5	1.5	4.8	1.5	4.3	ns
t <sub>PLZ</sub>			1.5	7.5	1.5	5	1.5	4.8	1.5	4.3	



PARAMETER MEASUREMENT INFORMATION



- NOTES: A.  $C_L$  includes probe and jig capacitance.  
 B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.  
 C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

**PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
5962-9221401M2A	ACTIVE	LCCC	FK	20	1	None	Call TI	Level-NC-NC-NC
5962-9221401MRA	ACTIVE	CDIP	J	20	1	None	Call TI	Level-NC-NC-NC
5962-9221403M2A	ACTIVE	LCCC	FK	20	1	None	Call TI	Level-NC-NC-NC
5962-9221403MRA	ACTIVE	CDIP	J	20	1	None	Call TI	Level-NC-NC-NC
5962-9221405M2A	ACTIVE	LCCC	FK	20	1	None	Call TI	Level-NC-NC-NC
5962-9221405MRA	ACTIVE	CDIP	J	20	1	None	Call TI	Level-NC-NC-NC
CY54FCT245ATDMB	ACTIVE	CDIP	J	20	1	None	Call TI	Level-NC-NC-NC
CY54FCT245CTLMB	ACTIVE	LCCC	FK	20	1	None	Call TI	Level-NC-NC-NC
CY54FCT245TLMB	ACTIVE	LCCC	FK	20	1	None	Call TI	Level-NC-NC-NC
CY74FCT245ATPC	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CY74FCT245ATQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CY74FCT245ATSOC	ACTIVE	SOIC	DW	20	25	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
CY74FCT245ATSOCT	ACTIVE	SOIC	DW	20	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
CY74FCT245CTQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CY74FCT245CTSOC	ACTIVE	SOIC	DW	20	25	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
CY74FCT245CTSOCT	ACTIVE	SOIC	DW	20	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
CY74FCT245DTQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CY74FCT245TQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CY74FCT245TSOC	ACTIVE	SOIC	DW	20	25	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
CY74FCT245TSOCT	ACTIVE	SOIC	DW	20	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - May not be currently available - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**None:** Not yet available Lead (Pb-Free).

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<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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DSP	<a href="http://dsp.ti.com">dsp.ti.com</a>	Broadband	<a href="http://www.ti.com/broadband">www.ti.com/broadband</a>
Interface	<a href="http://interface.ti.com">interface.ti.com</a>	Digital Control	<a href="http://www.ti.com/digitalcontrol">www.ti.com/digitalcontrol</a>
Logic	<a href="http://logic.ti.com">logic.ti.com</a>	Military	<a href="http://www.ti.com/military">www.ti.com/military</a>
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